#### MAX30002

# Ultra-Low-Power, Single-Channel Integrated Bioimpedance (BioZ) AFE

#### **General Description**

The MAX30002 is a complete bioimpedance (BioZ), analog front-end (AFE) solution for wearable applications. It offers high performance for clinical and fitness applications, with ultra-low-power for long battery life. The MAX30002 is a single bioimpedance channel capable of measuring respiration.

The bioimpedance channel has ESD protection, EMI filtering, internal lead biasing, DC leads-off detection, ultra-low-power leads-on detection during standby mode, and a programmable resistive load for built-in self-test. Soft power-up sequencing ensures no large transients are injected into the electrodes. The channel also has high input impedance, low noise, high CMRR, programmable gain, various low-pass and high-pass filter options, and a high resolution analog-to-digital converter. The bioimpedance channel includes integrated programmable current drive, works with common electrodes, and has the flexibility for 2 or 4 electrode measurements. It also has AC lead off detection.

The MAX30002 is available in a 28-pin TQFN and 30-bump wafer-level package (WLP), operating over the 0°C to +70°C commercial temperature range.

#### **Applications**

- Single-Lead Wireless Patches for In-Patient/Out-Patient Monitoring
- Respiration and Hydration Monitors
- Impedance Based Heart Rate Detection

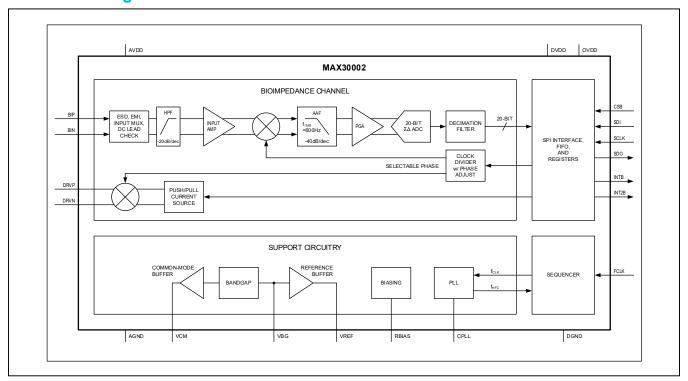
#### **Benefits and Features**

- BioZ AFE with High Resolution Data Converter
   17 Bits ENOB with 1.1µV<sub>P-P</sub> Noise for BioZ
- High AC Dynamic Range of 90mV<sub>P-P</sub> Will Help Prevent Saturation in the Presence of Motion/Direct Electrode Hits
- Longer Battery Life Compared to Competing Solutions
   158µW at 1.1V Supply Voltage
- Leads-On Interrupt Feature Allows to Keep µC in Deep Sleep Mode Until Valid Lead Condition is Detected
  - Lead-On Detect Current: 0.63µA (typ)
- High Accuracy Allows for More Physiological Data Extractions
- 8-Word FIFO Allows the MCU to Stay Powered Down for 256ms with Full Data Acquisition
- High-Speed SPI Interface
- Shutdown Current of 0.58µA (typ)

Ordering Information appears at end of data sheet.



# **Functional Diagram**



Junction-to-Ambient Thermal Resistance (θ<sub>JA</sub>) .......44°C/W

### **Absolute Maximum Ratings**

AVDD to AGND0.3V DVDD to DGND0.3V	1 \ \	70°C)
AVDD to DVDD0.3V		2758.6mW
OVDD to DGND0.3V	to +3.6V 30-Bump WLP	
AGND to DGND0.3V	to +0.3V (derate 24.3mW/°C above +70°C)	1945.5mW
CSB, SCLK, SDI, FCLK to DGND0.3V	to +3.6V Operating Temperature Range	0°C to +70°C
SDO, INTB, INT2B	Junction Temperature	+150°C
to DGND0.3V to the lower of (3.6V and OVDI		
All Other Pins	Lead Temperature (Soldering, 10sec)	
to AGND0.3V to the lower of (2.0V and AVDI	D + 0.3V) Soldering Temperature (reflow)	+260°C
Maximum Current into Any Pin		
Package Thermal Characteristics (	Note 1)	
TOFN	NA/L D	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Note 1:** Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

#### **Electrical Characteristics**

Junction-to-Ambient Thermal Resistance (θ<sub>JA</sub>)......29°C/W

Junction-to-Case Thermal Resistance (θ<sub>JC</sub>)......2°C/W

 $(V_{DVDD} = V_{AVDD} = +1.1V \text{ to } +2.0V, V_{OVDD} = +1.65V \text{ to } +3.6V, f_{FCLK} = 32.768 \text{kHz}, LN\_BIOZ = 1, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$  Typical values are at  $V_{DVDD} = V_{AVDD} = +1.8V, V_{OVDD} = +2.5V, T_A = +25^{\circ}C.)$  (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS				
BIOIMPEDANCE (BIOZ) CHANNEL										
Signal Generator Resolution		Square wave generator		1		Bits				
DRVP/N Injected Full-Scale Current		Programmable, see Register Map		8 to 96		μA <sub>P-P</sub>				
DRVP/N Injected Current		Internal bias resistor	-30		+30	%				
Accuracy		External bias resistor (0.1%, 10ppm, 324kΩ)	-10		+10	70				
DRVP/N Injected Current Power Supply Rejection				<±1		%/V				
DRVP/N Injected Current Temperatue Coefficient		External bias resistor, 32μA <sub>P-P</sub> , 0 to 70°C (0.1%, 10ppm, 324kΩ)		50		ppm/°C				
DRVP/N Compliance Voltage		V <sub>DRVP</sub> - V <sub>DRVN</sub>		±(V <sub>AVDD</sub> - 0.5)		V <sub>P-P</sub>				
Current Injection Frequency		Programmable, see Register Map		0.125 to 131.072		kHz				
AC D:#til.lt D		Shift from nominal gain < 1% (1.1V)		25		>/				
AC Differential Input Range		Shift from nominal gain < 1% (1.8V)		90		mV				
BioZ Channel Gain		Programmable, see Register Map		10 to 80		V/V				
ADC Sample Rate		Programmable, see Register Map		24.98 to 64		sps				

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PARAMETER	SYMBOL	CONDITIONS	MIN TYP MAX	UNITS	
ADC Resolution			20	Bits	
Input Referred Noise		BW = 0.05 to 4Hz, Gain = 20x	0.16	μV <sub>RMS</sub>	
(BIP, BIN)		BW = 0.05 to 4Hz, Gain = 20x	1.1	μV <sub>P-P</sub>	
Impedance Resolution		DC to 4Hz, $32\mu A_{P-P}$ , 40kHz, Gain = 20x, $R_{BODY}$ = $680\Omega$	40	mΩ <sub>P-P</sub>	
Input Analog High Pass Filter		Programmable, see Register Map	125 to 7200	Hz	
Demodulation Phase Range		Programmable, see Register Map	0-180	۰	
Demodulation Phase Resolution		Programmable, see Register Map	11.25	0	
		DLPF[1:0] = 01	4		
Output Digital Low Pass Filter		DLPF[1:0] = 10	8	Hz	
		DLPF[1:0] = 11	16	1	
Outsut Divital High Dass Filter		DHPF[1:0] = 01	0.05		
Output Digital High Pass Filter		DHPF[1:0] = 1x	0.5	Hz	
BIOIMPEDANCE (BIOZ) INPUT I	MUX		•		
		IMAG[2:0] = 001	5		
		IMAG[2:0] = 010	10	nA	
DC Lead Off Check		IMAG[2:0] = 011	20		
		IMAG[2:0] = 100	50		
		IMAG[2:0] = 101	100		
		VTH[1:0] = 11 (Note 4)	V <sub>MID</sub> – 0.50		
DC Lead Off Comparator Low		VTH[1:0] = 10 (Note 5)	V <sub>MID</sub> – 0.45		
Threshold		VTH[1:0] = 01 (Note 6)	V <sub>MID</sub> – 0.40	V	
		VTH[1:0] = 00	V <sub>MID</sub> – 0.30		
		VTH[1:0] = 11 (Note 4)	V <sub>MID</sub> + 0.50		
DC Lead Off Comparator High		VTH[1:0] = 10 (Note 5)	V <sub>MID</sub> + 0.45	1 ,,	
Threshold		VTH[1:0] = 01 (Note 6)	V <sub>MID</sub> + 0.40	V	
		VTH[1:0] = 00	V <sub>MID</sub> + 0.30		
		Lead bias enabled, RBIASV[1:0] = 00	50		
Lead Bias Impedance		Lead bias enabled, RBIASV[1:0] = 01	100	МΩ	
		Lead bias enabled, RBIASV[1:0] = 10	200		
Lead Bias Voltage		Lead bias enabled. Programmable, see Register Map	V <sub>AVDD</sub> / 2.15	V	

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Resistive Load Nominal Value	R <sub>VAL</sub>	Programmable, see Register Map		0.625 to 5.0		
Resistive Load Modulation Value	R <sub>MOD</sub>	Programmable, see Register Map		15 to 2960		
Resistive Load Modulation Frequency	F <sub>MOD</sub>	Programmable, see Register Map		0.625 to 4.0		Hz
INTERNAL REFERENCE/COM	MON-MODE					
V <sub>BG</sub> Output Voltage	$V_{BG}$			0.650		V
V <sub>BG</sub> Output Impedance				100		kΩ
External V <sub>BG</sub> Compensation Capacitor	C <sub>BG</sub>		1			μF
V <sub>REF</sub> Output Voltage	V <sub>REF</sub>	T <sub>A</sub> = +25°C	0.995	1.000	1.005	V
V <sub>REF</sub> Temperature Coefficient	TC <sub>REF</sub>	T <sub>A</sub> = 0°C to +70°C		10		ppm/°C
V <sub>REF</sub> Buffer Line Regulation				330		μV/V
V <sub>REF</sub> Buffer Load Regulation		I <sub>LOAD</sub> = 0 to 100μA		25		μV/μΑ
External V <sub>REF</sub> Compensation Capacitor	C <sub>REF</sub>		1	10		μF
VCM Output Voltage	V <sub>CM</sub>			0.650		V
External V <sub>CM</sub> Compensation Capacitor	C <sub>CM</sub>		1	10		μF
DIGITAL INPUTS (SDI, SCLK, C	SB, FCLK)		-			
Input-Voltage High	V <sub>IH</sub>		0.7 x V <sub>O</sub>	VDD		V
Input-Voltage Low	V <sub>IL</sub>			0.3 x '	√ovdd	V
Input Hysteresis	V <sub>HYS</sub>		0	.05 x V <sub>OVDD</sub>		V
Input Capacitance	C <sub>IN</sub>			10		pF
Input Current	I <sub>IN</sub>		-1		+1	μA
DIGITAL OUTPUTS (SDO, INTE	B, INT2B)					
Output Voltage High	V <sub>OH</sub>	I <sub>SOURCE</sub> = 1mA	V <sub>OVDD</sub> -	0.4		V
Output Voltage Low	V <sub>OL</sub>	I <sub>SINK</sub> = 1mA			0.4	V
Three-State Leakage Current			-1		+1	μA
Three-State Output Capacitance				15		pF

 $(V_{DVDD} = V_{AVDD} = +1.1V \text{ to } +2.0V, V_{OVDD} = +1.65V \text{ to } +3.6V, f_{FCLK} = 32.768 \text{kHz}, LN\_BIOZ = 1, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$  Typical values are at  $V_{DVDD} = V_{AVDD} = +1.8V, V_{OVDD} = +2.5V, T_A = +25^{\circ}C.)$  (Note 2)

PARAMETER	SYMBOL	cc	ONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY	•	•					•
Analog Supply Voltage	V <sub>AVDD</sub>	Connect AVDD to I	OVDD	1.1		2.0	V
Digital Supply Voltage	V <sub>DVDD</sub>	Connect DVDD to	AVDD	1.1		2.0	V
Interface Supply Voltage	V <sub>OVDD</sub>	Power for I/O drive	rs only	1.65		3.6	V
		BioZ channel ,	$V_{AVDD} = V_{DVDD} = +1.1V$		144		
		LN_BIOZ = 0	$V_{AVDD} = V_{DVDD} = +1.8V$		163		
			$V_{AVDD} = V_{DVDD} = +2.0V$		170	190	
Supply Current	I <sub>AVDD</sub> +	BioZ channel ,	$V_{AVDD} = V_{DVDD} = +1.1V$		158		μA
July July 1	I <sub>DVDD</sub>	LN_BIOZ = 1	$V_{AVDD} = V_{DVDD} = +1.8V$		178		
		CGMAG[2:0] = 011	V <sub>AVDD</sub> = V <sub>DVDD</sub> = +2.0V		185	205	
		ULP Lead On	T <sub>A</sub> = +70°C		1.3		
		Detect	T <sub>A</sub> = +25°C		0.63	2.5	
		V <sub>OVDD</sub> = +1.65V, BioZ channel at 64sps (Note 7)			0.1		
Interface Supply Current	lovdd	V <sub>OVDD</sub> = 3.6V, Bio (Note 7)		0.2	1.1	- μA	
	I <sub>SAVDD</sub> +	V <sub>AVDD</sub> = V <sub>DVDD</sub>	T <sub>A</sub> = +70°C		1.3		
Shutdown Current		= 2.0V	T <sub>A</sub> = +25°C		0.58	2.5	μA
	I <sub>SOVDD</sub>	V <sub>OVDD</sub> = 3.6V, V <sub>AVDD</sub> = V <sub>DVDD</sub> = 2.0V				1.1	
ESD PROTECTION							
		IEC 61000-4-2 Cor	IEC 61000-4-2 Contact Discharge (Note 8)		±8		
BIP, BIN, DRVP, DRVN		IEC 61000-4-2 Air-Gap Discharge (Note 8)			±15		kV
		HMM (Human Met		±8			
TIMING CHARACTERISTICS (I	NOTE 3)						
SCLK Frequency	fsclk			0		12	MHz
SCLK Period	t <sub>CP</sub>			83			ns
SCLK Pulse Width High	t <sub>CH</sub>			15			ns
SCLK Pulse Width Low	t <sub>CL</sub>						ns
CSB Fall to SCLK Rise Setup Time	t <sub>CSS0</sub>	To 1st SCLK rising edge (RE)		15			ns
CSB Fall to SCLK Rise Hold Time	t <sub>CSH0</sub>	Applies to inactive	0			ns	
CSB Rise to SCLK Rise Hold Time	t <sub>CSH1</sub>	Applies to 32nd RE	E, executed write	10			ns
CSB Rise to SCLK Rise	t <sub>CSA</sub>	Applies to 32nd RE	, aborted write sequence	15			ns

 $(V_{DVDD} = V_{AVDD} = +1.1V \text{ to } +2.0V, V_{OVDD} = +1.65V \text{ to } +3.6V, f_{FCLK} = 32.768 \text{kHz}, LN\_BIOZ = 1, T_A = T_{MIN} \text{ to } T_{MAX}, unless \text{ otherwise}$ noted. Typical values are at  $V_{DVDD} = V_{AVDD} = +1.8V$ ,  $V_{OVDD} = +2.5V$ ,  $T_A = +25$ °C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
SCLK Rise to CSB Fall	t <sub>CSF</sub>	Applies to 32nd RE	100			ns
CSB Pulse-Width High	t <sub>CSPW</sub>		20			ns
SDI-to-SCLK Rise Setup Time	t <sub>DS</sub>		8			ns
SDI to SCLK Rise Hold Time	t <sub>DH</sub>		8			ns
		C <sub>LOAD</sub> = 20pF			40	ns
SCLK Fall to SDO Transition	t <sub>DOT</sub>	$C_{LOAD}$ = 20pF, $V_{AVDD}$ = $V_{DVDD} \ge 1.8V$ , $V_{DVDD} \ge 2.5V$			20	ns
SCLK Fall to SDO Hold	t <sub>DOH</sub>	C <sub>LOAD</sub> = 20pF	2			ns
CSB Fall to SDO Fall	t <sub>DOE</sub>	Enable time, C <sub>LOAD</sub> = 20pF			30	ns
CSB Rise to SDO Hi-Z	t <sub>DOZ</sub>	Disable time			35	ns
FCLK Frequency	fFCLK	External reference clock		32.768		kHz
FCLK Period	t <sub>FP</sub>			30.52		μs
FCLK Pulse-Width High	t <sub>FH</sub>	50% duty cycle assumed		15.26		μs
FCLK Pulse-Width Low	t <sub>FL</sub>	50% duty cycle assumed		15.26		μs

- Note 2: All devices are 100% production tested at T<sub>A</sub> = +25°C. Specifications over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.
- Note 3: Guaranteed by design and characterization. Not tested in production.
- Note 4: Use this setting only for  $V_{AVDD} = V_{DVDD} \ge 1.65V$ .
- Note 5: Use this setting only for  $V_{AVDD} = V_{DVDD} \ge 1.55V$ .
- Note 6:
- Use this setting only for  $V_{AVDD} = V_{DVDD} \ge 1.45V$ .  $f_{SCLK} = 4MHz$ , burst mode, BFIT[2:0] = 111,  $C_{SDO} = C_{INTB} = 50pF$ . Note 7:
- ESD test performed with  $1k\Omega$  series resistor designed to withstand 8kV surge voltage. Note 8:

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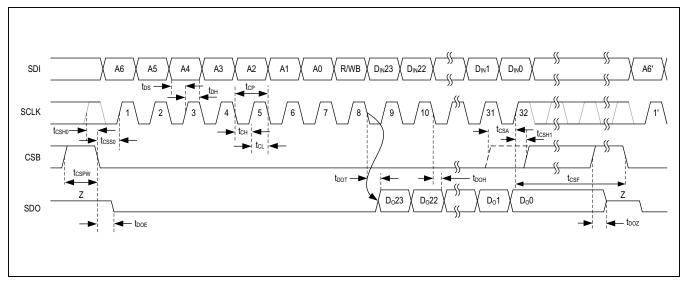


Figure 1a. SPI Timing Diagram

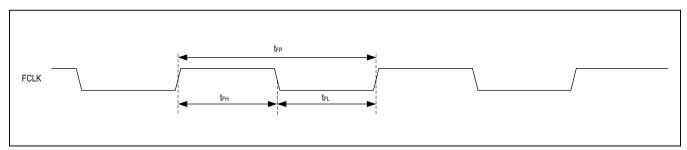
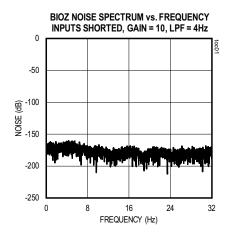
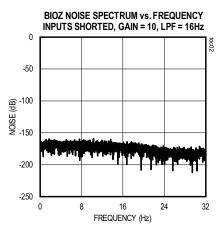


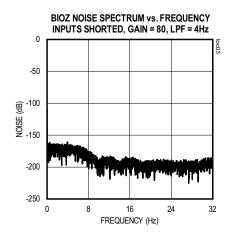
Figure 1b. FCLK Timing Diagram

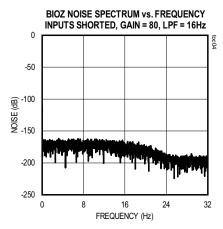
### **Typical Operating Characteristics**

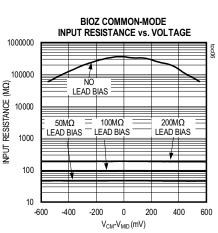
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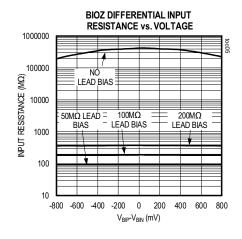


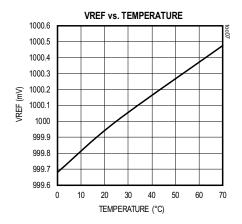






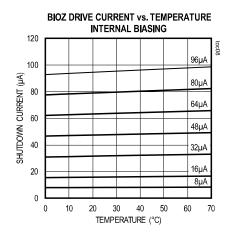


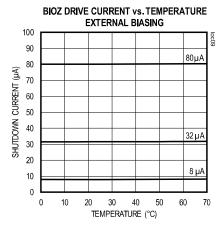


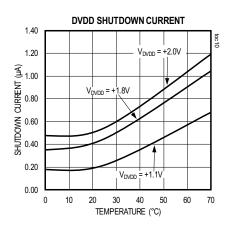


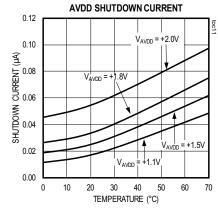
### **Typical Operating Characteristics (continued)**

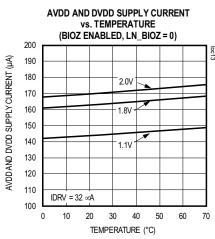
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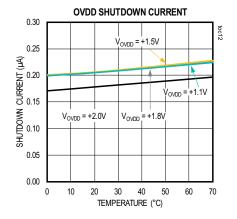


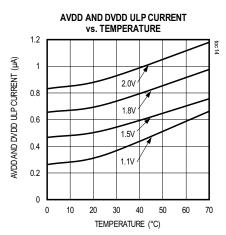




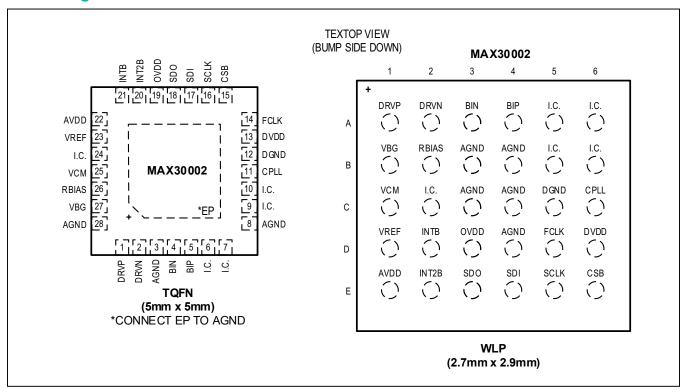








# **Pin Configurations**



# **Pin Description**

BUMP	PIN	NAME	FUNCTION			
WLP	WLP TQFN		FUNCTION			
A1	1	DRVP	Positive Output Current Source for Bio-Impedance Excitation. Requires a series capacitor between pin and electrode.			
A2	2	DRVN	Negative Output Current Source for Bio-Impedance Excitation. Requires a series capacitor between pin and electrode.			
A3	4	BIN	Bioimpedance Negative Input.			
A4	5	BIP	Bioimpedance Positive Input.			
A5, A6, B5, B6, C2	6, 7, 9, 10, 24	I.C.	Internally Connected. Connect to AGND.			
B1	27	VBG	Bandgap Noise Filter Output. Connect a 1.0μF X7R ceramic capacitor between VBG and AGND.			
B2	26	RBIAS	External Resistor Bias. Connect a low tempco resistor between RBIAS and AGND. If external bias generator is not used then RBIAS can be left floating.			
B3, B4, C3, C4, D4	3, 8, 28	AGND	Analog Power and Reference Ground. Connect into the printed circuit board ground plane.			
C1	25	VCM	Common Mode Buffer Output. Connect a 10µF X5R ceramic capacitor between VCM and AGND.			

# **Pin Description (continued)**

BUMP	PIN		TUNIOTION.
WLP	TQFN	NAME	FUNCTION
C5	12	DGND	Digital Ground for Both Digital Core and I/O Pad Drivers. Recommended to connect to AGND plane.
C6	11	CPLL	PLL Loop Filter Input. Connect 1nF capacitor between CPLL and AGND.
D1	23	VREF	ADC Reference Buffer Output. Connect a $10\mu F$ X5R ceramic capacitor between $V_{REF}$ and AGND.
D2	21	INTB	Interrupt Output. INTB is an active-low status output. It can be used to interrupt an external device. INTB is three-stated when disabled.
D3	19	OVDD	Logic Interface Supply Voltage.
D5	14	FCLK	32.768kHz Clock Input. FCLK Controls the sampling of the internal sigma-delta converter and decimator and derives all the internal clocks.
D6	13	DVDD	Digital Core Supply Voltage. Connect to AVDD.
E1	22	AVDD	Analog Core Supply Voltage. Connect to DVDD.
E2	20	INT2B	Interrupt 2 Output. INT2B is an active-low status output. It can be used to interrupt an external device. INT2B is three-stated when disabled.
E3	18	SDO	Serial Data Output. SDO will change state on the falling edge of SCLK when CSB is low. SDO is three-stated when CSB is high.
E4	17	SDI	Serial Data Input. SDI is sampled into the device on the rising edge of SCLK when CSB is low.
E5	16	SCLK	Serial Clock Input. Clocks data in and out of the serial interface when CSB is low.
E6	15	CSB	Active-Low Chip-Select Input. Enables the serial interface.
		_	Exposed Pad. Connect EP to AGND.

#### **Detailed Description**

#### **BioZ Channel**

Figure 2 illustrates the BioZ channel block diagram, excluding the ADC. The channel comprises an input MUX, a programmable analog high-pass filter, an instrumentation amplifier, a mixer, an anti-alias filter, and a programmable gain amplifier. The MUX includes several features such as ESD protection, EMI filtering, lead biasing, leads off checking, and ultra-low-power leads-on checking. The output of this analog channel drives a high-resolution ADC.

#### **Input MUX**

The BioZ input MUX shown in Figure 3 contains integrated ESD and EMI protection, DC leads off detect current sources and comparators, lead-on detect, series isolation switches, lead biasing, and a built-in programmable resistor load, for self test.

#### **EMI Filtering and ESD Protection**

EMI filtering of the BIP and BIN inputs consists of a single pole, low pass, differential, and common mode filter with the pole located at approximately 2MHz. The BIP and BIN inputs also have input clamps that protect the inputs from ESD events. The DRVP and DRVN outputs also feature ESD protection.

- ±8kV using the Contact Discharge method specified in IEC61000-4-2 ESD.
- ±15kV using the Air Gap Discharge method specified in IEC61000-4-2 ESD.
- ±8kV HMM

For IEC61000-4-2 ESD protection, use  $1k\Omega$  or larger series resistors on BIP, BIN, DRVP, and DRVN that are rated to withstand the appropriate surge voltages.

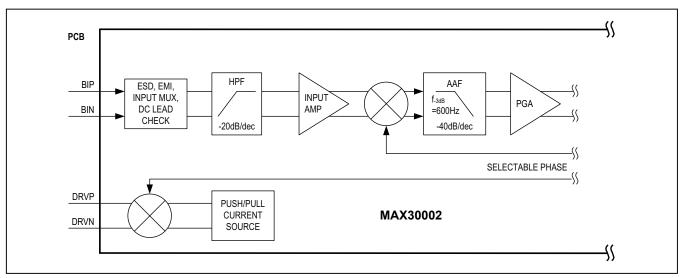


Figure 2. BioZ Channel Input Amplifier, Mixer, and PGA Excluding the ADC and Current Drive Output

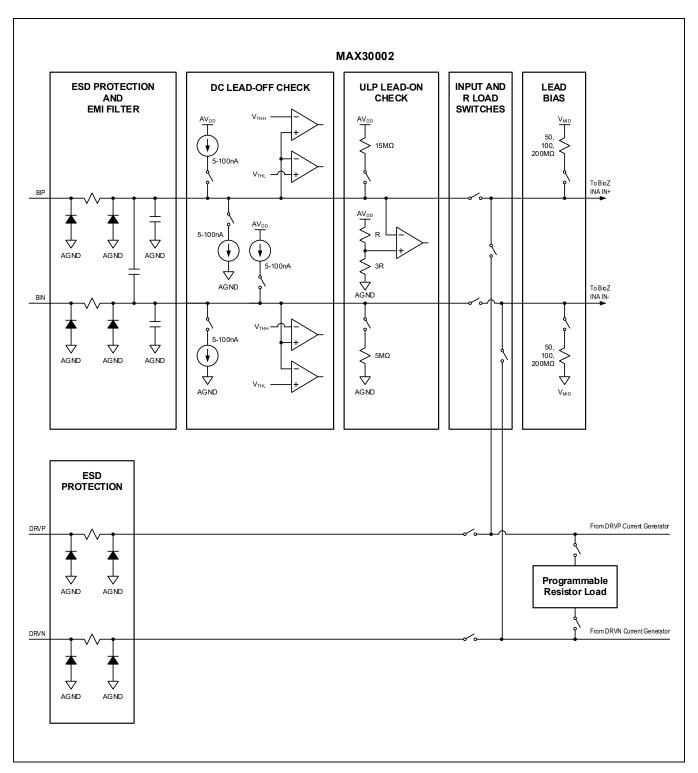


Figure 3. BioZ Input MUX

# Leads-Off Detection and ULP Leads-On Detection

MAX30002 provides the capability of detecting lead off scenarios that involve two electrode and four electrode configurations through the use of digital threshold and analog threshold comparisons. There are three methods to detect lead-off for the BioZ channel. There is a compliance monitor for the current generator on the DRVP and DRVN pins detecting when the voltage on the pins is outside its operating range. The CGMON bit in the CNFG BIOZ (0x18) register enables this function and the BCGMON, BCGMP, and BCGMN bits in the STATUS (0x01) register indicate if the DRVP and DRVN pins are out of compliance. There is a DC lead-off circuit on the BIP and BIN pins that sinks or sources a programmable DC current and window comparators with a programmable threshold to detect the condition. There is a digital lead off detection monitoring the output of the BioZ ADC with programmable under and overvoltage levels performing a digital comparison. The EN BLOFF bit in the CNFG GEN (0x10) register enables this function and the BLOFF HI IT[7:0] and BLOFF LO IT[7:0] bits in the MNGR\_DYN (0x05) register sets the digital threshold for detection. Refer to Table 1 for lead off conditions and register settings to allow detection.

The ULP lead-on detect operates by pulling BIN low with a pulldown resistance larger than  $5M\Omega$  and pulling BIP high with a pullup resistance larger than  $15M\Omega$ . A low-power comparator determines if BIP is pulled below a predefined threshold that occurs when both electrodes make contact with the body. When the impedance between BIP and BIN is less than  $20M\Omega$ , the LONINT status bit is asserted, and when the interrupt is enabled on either the INTB or INT2B pin, will alert the  $\mu$ C to a leads-on condition.

A  $0nA/V_{MID} \pm 300mV$  selection is available allowing monitoring of the input compliance of the INA during non-DC lead-off checks.

**Table 1. BioZ Lead Off Detection Configurations** 

CONFIGURATION	CONDITION	DRVP/N	BIP/N	MEASURED SIGNAL	REGISTER SETTING TO DETECT
Two-Electrode (Shared DRV/BI)	1 Electrode Off	Rail to Rail	Rail to Rail	Rail to Rail (Saturated Inputs)	CNFG_GEN (0x10), EN_BLOFF[1:0] = 10 or 11 MNGR_DYN (0x05), BLOFF_HI_IT[7:0]
	1 DRV Electrode Off, Large Body Coupling	Rail to Rail	Normal	½ Signal	CNFG_BIOZ (0x18), CGMON = 1
Four-Electrode	1 DRV Electrode Off, Small Body Coupling	Rail to Rail	Rail to Rail	Rail to Rail (Saturated Inputs)	CNFG_GEN (0x10), EN_BLOFF[1:0] = 10 or 11 MNGR_DYN (0x05), BLOFF_HI_IT[7:0]
(Force/Sense)	1 BI (sense) Electrode Off	Normal	Floating	½ Signal	CNFG_GEN (0x10), EN_DCLOFF = 10
	Both BIP/N (sense) Electrodes Off	Normal	Floating	No Signal	CNFG_GEN (0x10), EN_BLOFF[1:0] = 01 or 11 MNGR_DYN (0x05), BLOFF_LO_IT[7:0]
	1 DRV and 1 BI Electrode Off	Rail to Rail	Wide Swing, Dependent on Body Coupling	Rail to Rail	CNFG_GEN (0x10), EN_BLOFF[1:0] = 10 or 11 MNGR_DYN (0x05), BLOFF_HI_IT[7:0]

#### **Lead Bias**

The MAX30002 limits the BIP and BIN DC input common mode range to  $V_{\mbox{\scriptsize MID}}$  ±150mV. This range can be maintained either through external/internal lead-biasing.

Internal DC lead-biasing consists of  $50M\Omega$ ,  $100M\Omega$ , or  $200M\Omega$  selectable resistors to  $V_{MID}$  that drive the electrodes within the input common mode requirements of the BioZ channel and can drive the connected body to the proper common mode voltage level. See the EN\_RBIAS[1:0], RBIASV[1:0], RBIASP, and RBIASN bits in the CNFG\_GEN (0x10) register to select a configuration.

The common-mode voltage,  $V_{CM}$ , can optionally be used as a body bias to drive the body to the common-mode voltage by connecting  $V_{CM}$  to a separate electrode on the body through a high value resistor such as  $1M\Omega$  to limit curent into the body. If this is utilized then the internal lead bias resistors to  $V_{MID}$  can be disabled.

#### **Programmable Resistive Load**

The programmable resistive load on the DRVP/DRVN pins allows a built in self-test of the current generator (CG) and the entire BioZ channel. Refer to Figure 4 for implementation details.

Nominal resistance can be varied between  $5k\Omega$  and  $625\Omega$ . The modulation resistance is dependent on the nominal resistance value with resolution of  $247.5m\Omega$  to  $2.96\Omega$  at the largest nominal resistance  $(5k\Omega)$  and  $15.3m\Omega$  to  $46.3m\Omega$  with the smallest nominal resistance  $(625\Omega)$ . Refer to Table 2 for a complete listing of nominal and modulated resistor values. Modulation rate can be programmed between 62.5mHz to 4Hz.

See register CNFG\_BMUX (0x17) to select the configuration for modulation rate and resistor value.

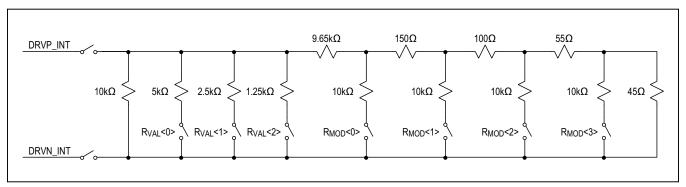


Figure 4. Programmable Resistive Load Topology

**Table 2. Programmable Resistive Load Values** 

B (O)	R <sub>MOD</sub>		R <sub>VAL</sub> R <sub>MOD</sub>			R <sub>MOD</sub>		
$R_{NOM}(\Omega)$		<2>	<1>	<0>	<3>	<2>	<1>	<0>
	-	0	0	0	0	0	0	0
E000 000	2960.7	0	0	0	0	0	0	1
5000.000	980.6	0	0	0	0	0	1	0
	247.5	0	0	0	0	1	0	0
	_	0	0	1	0	0	0	0
0500 000	740.4	0	0	1	0	0	0	1
2500.000	245.2	0	0	1	0	0	1	0
	61.9	0	0	1	0	1	0	0
	_	0	1	0	0	0	0	0
4000 007	329.1	0	1	0	0	0	0	1
1666.667	109.0	0	1	0	0	0	1	0
	27.5	0	1	0	0	1	0	0
	_	0	1	1	0	0	0	0
1250.000	185.1	0	1	1	0	0	0	1
	61.3	0	1	1	0	0	1	0
	_	1	0	0	0	0	0	0
1000.000	118.5	1	0	0	0	0	0	1
	39.2	1	0	0	0	0	1	0
	_	1	0	1	0	0	0	0
833.333	82.3	1	0	1	0	0	0	1
	27.2	1	0	1	0	0	1	0
	_	1	1	0	0	0	0	0
714.286	60.5	1	1	0	0	0	0	1
	20.0	1	1	0	0	0	1	0
	_	1	1	1	0	0	0	0
625.000	46.3	1	1	1	0	0	0	1
	15.3	1	1	1	0	0	1	0

#### **Current Generator**

The current generator provides square-wave modulating differential current that is AC injected into the body via pins DRVP and DRVN with the bio-impedance sensed differentially through pins BIP and BIN. Two and four electrode configurations are supported for typical wet and dry electrode impedances.

Current amplitudes between  $8\mu A_{PK}$  to  $96\mu A_{PK}$  are selectable with current injection frequencies between 128Hz and 131.072kHz in power of two increments. See register CNFG\_BIOZ (0x18) for configuration selections.

Current amplitude should be chosen so as not exceed  $90\text{mV}_{\text{P-P}}$  at the BIP and BIN pins based on the network impedance at the current injection frequency. A 47nF DC blocking capacitor is required between both DRVP and DRVN and their respective electrodes.

# Current Selection and Resolution Calculation Example 1 (Two Terminal with Common Protection)

Selection of the appropriate current is accomplished by first calculating the network impedance at the injection frequency. Worst case electrode impedances should be used.

Given Figure 5 and a current injection frequency of 80kHz, the network impedance is:

$$R_{BODY} + 2R_{P1} + 2R_{P2} + 2R_S + \frac{2R_E}{1 + j\omega R_E C_E} = 2.8k\Omega$$

where  $R_{BODY}$  = 100 $\Omega$ ,  $R_{P1}$  = 1k $\Omega$ ,  $R_{P2}$  = 200 $\Omega$ ,  $R_{S}$  = 100 $\Omega$ ,  $R_{E}$  = 1M $\Omega$ ,  $C_{E}$  = 5nF. The maximum current injection is the maximum AC input differential range (90mV<sub>PK</sub>) divided by the network impedance (2.8k $\Omega$ ) or 32.14µA<sub>PK</sub>. The closest selectable lower value is 32µA<sub>PK</sub>.

Given the current injection value and the channel bandwidth (refer to register CNFG\_BIOZ (0x18) for digital LPF selection) the resolvable impedance can be calculated by dividing the appropriate input referred noise by the current injection value. For example, with a bandwidth of 4Hz, the input referred noise with a gain of 20V/V is  $0.16\mu V_{RMS}$  or  $1.1\mu V_{P-P}$ . The resolvable impedance is, therefore,  $1.1\mu V_{P-P}/32\mu A_{PK} = 34m\Omega_{P-P}$  or  $5m\Omega_{RMS}$ .

# **Current Selection and Resolution Calculation Example 2 (Four Terminal)**

Selection of the appropriate current is accomplished by first calculating the network impedance at the injection frequency. Worst case electrode impedances should be used.

Given Figure 6 and a current injection frequency of 80kHz, the network impedance is:

$$R_{BODY} + 2R_{DP1} + 2R_{DP2} + 2R_S + \frac{2R_E}{1 + j_{\omega}R_EC_E} = 2.7k\Omega$$

where  $R_{BODY}$  = 100 $\Omega$ ,  $R_{DP1}$  = 1k $\Omega$ ,  $R_{DP2}$  = 200 $\Omega$ ,  $R_{S}$  = 100 $\Omega$ ,  $R_{E}$  = 1M $\Omega$ ,  $C_{E}$  = 5nF. The maximum current injection is the maximum DRVP/N Compliance Voltage (V<sub>DD</sub>-0.5V = 0.6V for V<sub>DD</sub> = 1.1V) divided by the network impedance (2.7k $\Omega$ ) or 222.2 $\mu$ ApK. The closest selectable lower value is 96 $\mu$ ApK.

Given the current injection value and the channel bandwidth (refer to register CNFG\_BIOZ (0x18) for digital LPF selection) the resolvable impedance can be calculated by dividing the appropriate input referred noise by the current injection value. For example, with a bandwidth of 4Hz, the input referred noise with a gain of 40V/V is  $0.12\mu V_{RMS}$  or  $0.78\mu V_{P-P}$ . The resolvable impedance is therefore  $0.78\mu V_{P-P}/96\mu A_{PK}=8m\Omega_{P-P}$  or  $1.2m\Omega_{RMS}$ .

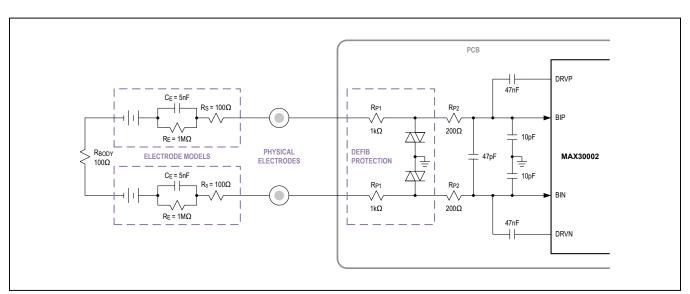


Figure 5. Example Configuration - Two Terminal with Common Protection

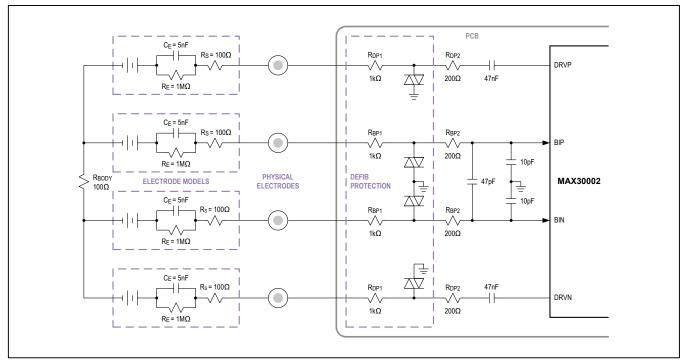


Figure 6. Example Configuration—Four Terminal

#### **Filter Section**

The filter section consists of an FIR decimation filter to to convert the ADC sample rate to the final data rate, followed by a programmable IIR and FIR filter to implement HPF and LPF selections, respectively.

The high-pass filter options include a fourth-order IIR Butterworth filter with a 0.05Hz or 0.5Hz corner frequency along with a pass through setting for DC coupling. Lowpass filter options include a 12-tap linear phase (constant group delay) FIR filter with 4Hz, 8Hz, or 16Hz corner frequencies. See register CNFG\_BIOZ (0x18) to configure the filters. Table 3 illustrates the BioZ latency in samples and time for each ADC data rate.

#### **Noise Measurements**

<u>Table 4</u> shows the noise performance of the BioZ channel of MAX30002 referred to the BioZ inputs.

#### **Reference and Common Mode Buffer**

The MAX30002 features internally generated reference voltages. The bandgap output ( $V_{BG}$ ) pin requires an external 1.0µF capacitor to AGND and the reference output ( $V_{REF}$ ) pin requires a 10µF external capacitor to AGND for compensation and noise filtering.

A common-mode buffer is provided to buffer 650mV which is used to drive common mode voltages for internal blocks. Use a 10µF external capacitor between  $V_{CM}$  to AGND to provide compensation and noise filtering. The common-mode voltage,  $V_{CM}$ , can optionally be used as a body bias to drive the body to the common-mode voltage by connecting  $V_{CM}$  to a separate electrode on the body through a high value resistor such as  $1M\Omega.$  If this is utilized then the internal lead bias resistors to  $V_{MID}$  may be disabled if the input signals are within the common-mode input range.

Table 3. BioZ Latency in Samples and Time as a Function of BioZ Data Rate and Decimation

BIOZ	CHANNEL SETTI	NGS	LATENCY				
INPUT SAMPLE RATE (Hz)	OUTPUT DATA RATE (sps)	DECIMATION RATIO	WITHOUT LPF (INPUT SAMPLES)	WITH LPF (INPUT SAMPLES)	WITHOUT LPF(ms)	WITH LPF (ms)	
32,768	64	512	3,397	6,469	103.668	197.418	
32,000	62.5	512	3,397	6,469	106.156	202.156	
32,000	50	640	5,189	9,029	162.156	282.156	
31,968	49.95	640	5,189	9,029	162.319	282.439	
32,768	32	1,024	7,557	13,701	230.621	418.121	
32,000	31.25	1,024	7,557	13,701	236.156	428.156	
32,000	25	1,280	9,605	17,285	300.156	540.156	
31,968	24.975	1,280	9,605	17,285	300.457	540.697	

**Table 4. BioZ Channel Noise Performance** 

GAIN	BANDWIDTH	NC	DISE	SNR	ENOB
V/V	Hz	μV <sub>RMS</sub>	μV <sub>P-P</sub>	dB	Bits
	4	0.23	1.55	101.6	16.6
10	8	0.28	1.87	100.0	16.3
	16	0.35	2.34	98.0	16.0
	4	0.16	1.10	104.9	17.1
20	8	0.19	1.27	103.4	16.9
	16	0.26	1.68	100.9	16.5
	4	0.12	0.78	107.6	17.6
40	8	0.16	1.07	104.9	17.1
	16	0.22	1.48	102.0	16.7
	4	0.11	0.72	108.3	17.7
80	8	0.15	1.01	105.3	17.2
	16	0.21	1.42	102.4	16.7

 $SNR = 20log(V_{IN}(RMS)/V_N(RMS)), \ ENOB = (SNR - 1.76)/6.02$ 

 $V_{INP-P}$  = 100mV,  $V_{INRMS}$  = 35.4mV for a gain of 10V/V. The input amplitude is reduced accordingly for high gain settings.

#### **SPI Interface Description**

#### 32 Bit Normal Mode Read/Write Sequences

The MAX30002 interface is SPI/QSPI/Micro-wire/DSP compatible. The operation of the SPI interface is shown in Figure 1a. Data is strobed into the MAX30002 on SCLK rising edges. The device is programmed and accessed by a 32 cycle SPI instruction framed by a CSB low interval. The content of the SPI operation consists of a one byte command word (comprised of a seven bit address and a Read/Write mode indicator, i.e., A[6:0] + R/W) followed by a three-byte data word. The MAX30002 is compatible with CPOL = 0/CPHA = 0 and CPOL = 1/CPHA = 1 modes of operation.

Write mode operations will be executed on the 32nd SCLK rising edge using the first four bytes of data available. In write mode, any data supplied after the 32nd SCLK rising edge will be ignored. Subsequent writes require CSB to de-assert high and then assert low for the next write command. In order to abort a command sequence, the rise of CSB must precede the updating (32nd) rising-edge of SCLK, meeting the  $t_{CSA}$  requirement.

Read mode operations will access the requested data on the 8th SCLK rising edge, and present the MSB of the requested data on the following SCLK falling edge, allowing the  $\mu$ C to sample the data MSB on the 9th SCLK rising edge. Configuration, Status, and FIFO data are all available via normal mode read back sequences. If more than 32 SCLK rising edges are provided in a normal read sequence then the excess edges will be ignored and the device will read back zeros.

If accessing the STATUS register or the BIOZ FIFO memory, all interrupt updates will be made and the internal FIFO read pointer will be incremented in response to the 30th SCLK rising edge, allowing for internal synchronization operations to occur. See the data tag structures used within the FIFO for means of detecting end-of-file (EOF) samples, invalid (empty samples) and other aides for efficiently using and managing normal mode read back operations.

#### **Burst Mode Read Sequence**

The MAX30002 provides commands to read back the BIOZ FIFO memory in a burst mode to increase data transfer efficiency. Burst mode uses different register addresses than the normal read sequence register addresses. The first 32 SCLK cycles operate exactly as described for the normal mode. If the  $\mu$ C continues to provide SCLK edges beyond the 32nd rising edge, the MSB of the next available FIFO word will be presented on the next falling SCLK edge, allowing the  $\mu$ C to sample the MSB of the next word on the 33rd SCLK rising edge. Any affected interrupts and/or FIFO read pointers will be incremented in response to the (30+nx24)th SCLK rising edge where n is an integer starting at 0. (i.e., on the 30th, 54th, and 78th SCLK rising-edges for a three-word, burst-mode transfer).

This mode of operation will continue for every 24 cycle sub frame, as long as there is valid data in the FIFO. See the data tag structures used within each FIFO for means of detecting end-of-file (EOF) samples, invalid (empty samples) and other aides for efficiently using and managing burst mode read back operations.

There is no burst mode equivalent in write mode.

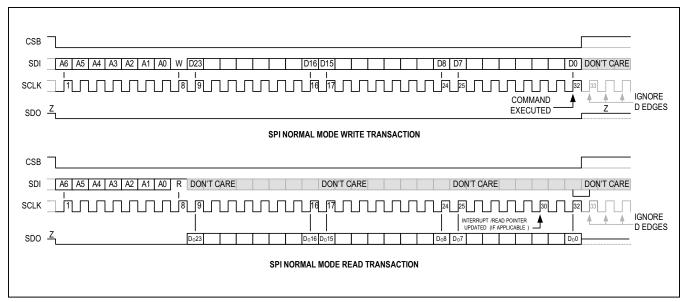


Figure 7. SPI Normal Mode Transaction Diagram

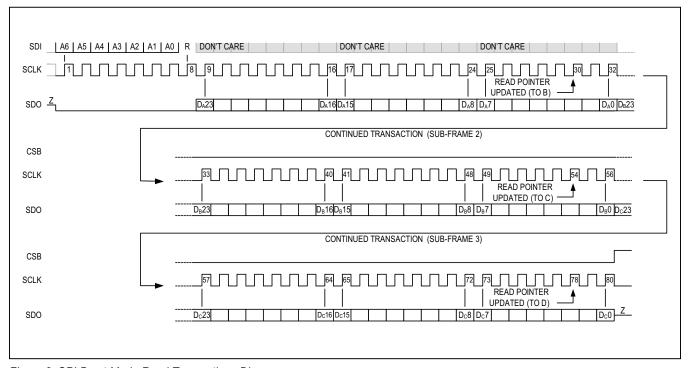


Figure 8. SPI Burst Mode Read Transactions Diagram

# **User Command and Register Map**

REG		R/W				D.A	ATA INDEX		18/10/2 17/9/1 16/8/0 x/x/x x/x/x x/x/x BOVE BOVED BUNDE			
[6:0]	NAME	MODE	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0		
0x00	NO-OP	R/W	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x		
			х	х	х	DCLO FFINT	BINT	BOVF	X/X/X BOVER SAMP LDOFF_NH EN_BOVER EN_SAMP INTB_T BFIT[2:0] X SAMP X  ID[3:0] X X X IMAG[2:0] RBIASP CALN_ RNOM[2:0] FBIS	BUNDR		
0x01	STATUS	R	BCGMON	х	х	х	LONINT	Х	SAMP	PLLINT		
			х	х	BCGMP	BCGMN	LDOFF_PH	LDOFF_PL	LDOFF_NH	LDOFF_NL		
0x02	EN_INT		х	х	x	EN_ DCLOFFINT	EN_BINT	EN_BOVF	EN_BOVER	EN_BUNDR		
0x03	EN_INT2	R/W	EN_BCGMON	х	х	х	EN_LONINT	Х	EN_SAMP	EN_ PLLINT		
			х	х	х	х	Х	x INTB_TYPE[1:0]				
			х	х	х	х	Х					
0x04	MNGR_INT	R/W	х	х	х	х	Х	Х	х	х		
			х	х	х	х	CLR_PEDGE	CLR_ SAMP	SAMP_	_IT[1:0]		
			х	х	х	х	х	Х	х	х		
0x05	MNGR_ DYN	R/W				BLOI	F_HI_IT[7:0]					
	5111					BLOF	F_LO_IT[7:0]					
0x08	SW_RST	W			С	ata Required for	or Execution = 0	x000000	00			
0x09	SYNCH	W			D	ata Required f	or Execution = 0	x000000				
0x0A	FIFO_RST	W				ata Required for	or Execution = 0	x000000				
			0	1	0	1		REV_	ID[3:0]			
0x0F	INFO	R	х	Х	1	0	Х	Х	Х	Х		
			x	Х	х	х	х	Х	Х	х		
			EN_ULP_L	ON[1:0]	FMS	TR[1:0]	Х	EN_BIOZ	Х	Х		
0x10	CNFG_GEN	R/W	EN_BLOF	F[1:0]	EN_DC	LOFF[1:0]	IPOL		IMAG[2:0]			
			VTH[1	:0]	EN_R	BIAS[1:0]	RBIAS	SV[1:0]	RBIASP	RBIASN		
	CNEC		х	Х	OPENP	OPENN	CALP_S	SEL[1:0]	CALN_S	SEL[1:0]		
0x17	CNFG_ BMUX	R/W	х	Х	CG_M	ODE[1:0]	EN_BIST		RNOM[2:0]			
			х		RMOD[2:0	]	х	Х	FBIS <sup>-</sup>	Γ[1:0]		
	CNFG_		RATE		AHPF[2:0]		EXT_RBIAS	LN_BIOZ	GAIN	I[1:0]		
0x18	BIOZ	R/W	DHPF[1	1:0]	DLF	PF[1:0]		FCGE	EN[3:0]			
	2.02		CGMON		CGMAG[2:	0]		PHOF	FF[3:0]			
0x22	BIOZ_ FIFO_ BURST	R+	BIOZ	FIFO Burst N	Mode Read B	Back		PHOFF[3:0]  See FIFO Description for details				
0x23	BIOZ_FIFO	R	BIOZ F	IFO Normal	Mode Read	Back		See FIFO Desc	:0] RBIASP RBIASN [1:0] CALN_SEL[1:0]  RNOM[2:0]  X FBIST[1:0]  .N_BIOZ GAIN[1:0]  FCGEN[3:0]  PHOFF[3:0]			
0x7F	NO-OP	R/W	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x	x/x/x		

Note: R/W Mode R+ denotes burst mode.

x = Don't Care

### **Register Description**

#### NO\_OP (0x00 and 0x7F) Registers

No Operation (NO\_OP) registers are read-write registers that have no internal effect on the device. If these registers are read back, DOUT remains zero for the entire SPI transaction. Any attempt to write to these registers is ignored without impact to internal operation.

### STATUS (0x01) Register

STATUS is a read-only register that provides a comprehensive overview of the current status of the device. The first two bytes indicate the state of all interrupt bits (regardless of whether interrupts are enabled in registers EN\_INT (0x02) or EN\_INT2 (0x03)). All interrupt bits are active high. The last byte includes detailed status information for conditions associated with the other interrupt bits.

#### Table 5. STATUS (0x01) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
		R	х	Х	Х	DCLOFF INT	BINT	BOVF	BOVER	BUNDR
0x01	STATUS		BCGMON	х	х	х	LONINT	х	SAMP	PLLINT
UXUT	01/1100	1	х	х	BCGMP	BCGMN	LDOFF_ PH	LDOFF_ PL	LDOFF_ NH	LDOFF_ NL

### Table 6. Status (0x01) Register Meaning

INDEX	NAME	MEANING
D[20]	DCLOFFINT	DC Lead-Off Detection Interrupt. Indicates that the MAX30002 has determined it is in a BioZ leads off condition (as selected in CNFG_GEN) for more than 90ms. Remains active as long as the leads-off condition persists, then held until cleared by STATUS read back (32nd SCLK).
D[19]	BINT	BIOZ FIFO Interrupt. Indicates BIOZ records meeting/exceeding the BIOZ FIFO Interrupt Threshold (BFIT) are available for read back. Remains active until BIOZ FIFO is read back to the extent required to clear the BFIT condition.
D[18]	BOVF	BIOZ FIFO Overflow. Indicates the BIOZ FIFO has overflowed and the data record has been corrupted. Remains active until a FIFO Reset (recommended) or SYNCH operation is issued.
D[17]	BOVER	BIOZ Over Range. Indicates the BIOZ output magnitude has exceeded the BIOZ High Threshold (BLOFF_HI_IT) for at least 100ms, recommended for use in 2 and 4 electrode BIOZ Lead Off detection. Remains active as long as the condition persists, then held until cleared by STATUS read back (32nd SCLK).
D[16]	BUNDR	BIOZ Under Range. Indicates the BIOZ output magnitude has been bounded by the BIOZ Low Threshold (BLOFF_LO_IT) for at least 1.7 seconds, recommended for use in 4 electrode BIOZ Lead Off detection. Remains active as long as the condition persists, then held until cleared by STATUS read back (32nd SCLK).
D[15]	BCGMON	BIOZ Current Generator Monitor. Indicates the DRVP and/or DRVN current generator has been in a Lead Off condition for at least 128ms, recommended for use in 4 electrode BIOZ Lead Off detection. Remains active as long as the condition persists, then held until cleared by STATUS read back (32nd SCLK).

Table 6. Status (0x01) Register Meaning (continued)

INDEX	NAME	MEANING
D[11]	LONINT	Ultra-Low Power (ULP) Leads-On Detection Interrupt. Indicates that the MAX30002 has determined it is in a leads-on condition (as selected in CNFG_GEN).  LONINT is asserted whenever EN_ULP_LON[1:0] in register CNFG_GEN is set to either 01 or 10 to indicate that the ULP leads on detection mode has been enabled. The STATUS register has to be read back once after ULP leads on detection mode has been activated to clear LONINT and enable leads on detection.  LONINT remains active while the leads-on condition persists, then held until cleared by STATUS read back (32nd SCLK).
D[9]	SAMP	Sample Synchronization Pulse. Issued on the BioZ base-rate sampling instant, for use in assisting µC monitoring and synchronizing other peripheral operations and data, generally recommended for use as a dedicated interrupt.  Frequency is selected by SAMP_IT[1:0], see MNGR_INT for details.  Clear behavior is defined by CLR_SAMP, see MNGR_INT for details.
D[8]	PLLINT	PLL Unlocked Interrupt. Indicates that the PLL has not yet achieved or has lost its phase lock. PLLINT will only be asserted when the PLL is powered up and active (BIOZ Channel enabled). Remains asserted while the PLL unlocked condition persists, then held until cleared by STATUS read back (32nd SCLK).
D[5]	BCGMP	BIOZ Current Generator Monitor Positive Output. Indicates the DRVP current generator has been in a Lead Off condition for at least 128ms. This is not strictly an interrupt bit, but is a detailed status bit, covered by the BCGMON interrupt bit.
D[4]	BCGMN	BIOZ Current Generator Monitor Negative Output. Indicates the DRVN current generator has been in a Lead Off condition for at least 128ms. This is not strictly an interrupt bit, but is a detailed status bit, covered by the BCGMON interrupt bit.
D[3]	LDOFF_PH	DC Lead Off Detection Detailed Status. Indicates that the MAX30002 has determined
D[2]	LDOFF_PL	(as selected by CNFG_GEN):  BIP is above the high threshold (V <sub>THH</sub> ), BIP is below the low threshold (V <sub>THL</sub> ), BIN is above the high
D[1]	LDOFF_NH	threshold (VT <sub>HH</sub> ), BIN is below the low threshold (V <sub>THL</sub> ), respectively.  Remains active as long as the leads-off detection is active and the leads-off condition persists, then
D[0]	LDOFF_NL	held until cleared by STATUS read back (32nd SCLK). LDOFF_PH to LDOFF_NL are detailed status bits that are asserted at the same time as DCLOFFINT.

#### EN\_INT (0x02) and EN\_INT2 (0x03) Registers

EN\_INT and EN\_INT2 are read/write registers that govern the operation of the INTB output and INT2B output, respectively. The first two bytes indicate which interrupt input bits are included in the interrupt output OR term (ex. a one in an EN\_INT register indicates that the corresponding input bit is included in the INTB interrupt output OR term). See the STATUS register for detailed descriptions of the interrupt bits. The power-on reset state of all EN\_INT bits is 0 (ignored by INT).

EN\_INT and EN\_INT2 can also be used to mask persistent interrupt conditions in order to perform other interrupt-driven operations until the persistent conditions are resolved.

INTB\_TYPE[1:0] allows the user to select between a CMOS or an open-drain NMOS mode INTB output. If using open-drain mode, an option for an internal  $125k\Omega$  pullup resistor is also offered.

All INTB and INT2B types are active-low (INTB low indicates the device requires servicing by the  $\mu$ C); however, the open-drain mode allows the INTB line to be shared with other devices in a wired-or configuration.

In general, it is suggested that INT2B be used to support specialized/dedicated interrupts of use in specific applications, such as the self-clearing versions of SAMP or RRINT.

Table 7. EN INT (0x02) and EN INT2 (0x03) Register Maps

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
		х	х	х	EN_DCL OFFINT	EN_BINT	EN_BOVF	EN_ BOVER	EN_ BUNDR	
0x02 0x03	0x02	R/W	EN_ BCGMON	х	х	х	EN_ LONINT	х	EN_ SAMP	EN_ PLLINT
			Х	Х	Х	х	х	Х	INTB_T	YPE[1:0]

Table 8. EN\_INT (0x02 and 0x03) Register Meaning

INDEX	NAME	DEFAULT	FUNCTION
D[23:8]	EN_DCLOFFINT EN_BINT EN_BOVF EN_BOVER EN_BUNDR EN_BCGMON EN_LONINT EN_SAMP EN_PLLINT	0x0000	Interrupt Enables for interrupt bits in STATUS[23:8] 0 = Individual interrupt bit is not included in the interrupt OR term 1 = Individual interrupt bit is included in the interrupt OR term
		11	INTB Port Type (EN_INT Selections) 00 = Disabled (Three-state) 01 = CMOS Driver 10 = Open-Drain NMOS Driver 11 = Open-Drain NMOS Driver with Internal 125kΩ Pullup Resistance
D[1:0]	INTB_TYPE[1:0]	11	INT2B Port Type (EN_INT2 Selections) 00 = Disabled (three-state) 01 = CMOS Driver 10 = Open-Drain nMOS Driver 11 = Open-Drain nMOS Driver with Internal 125kΩ Pullup Resistance

#### MNGR\_INT (0x04)

MNGR\_INT is a read/write register that manages the operation of the configurable interrupt bits in response to BIOZ FIFO conditions (see the STATUS register and BIOZ FIFO descriptions for more details).

Table 9. MNGR\_INT (0x04) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
1 0204 1		- R/W	х	х	х	х	х		BFIT[2:0]	
	MNGR_		х	х	х	х	х	х	х	х
	INT		х	CLR_ FAST	х	х	х	CLR_ SAMP	SAMP_	_IT[1:0]

#### Table 10. MNGR\_INT (0x04) Register Functionality

INDEX	NAME	DEFAULT	FUNCTION
D[18:16]	BFIT[2:0]	011	BIOZ FIFO Interrupt Threshold (issues BINT based on number of unread FIFO records) 000 to 111 = 1 to 8, respectively (i.e. BFIT[2:0]+1 unread records)
D[2]	CLR_SAMP	1	Sample Synchronization Pulse (SAMP) Clear Behavior:  0 = Clear SAMP on STATUS Register Read Back (recommended for debug/evaluation only).  1 = Self-clear SAMP after approximately one-fourth of one data rate cycle.
D[1:0]	SAMP_IT[1:0]	00	Sample Synchronization Pulse (SAMP) Frequency 00 = issued every sample instant 01 = issued every 2nd sample instant 10 = issued every 4th sample instant 11 = issued every 16th sample instant

#### MNGR\_DYN (0x05)

MNGR\_DYN is a read/write register that manages the settings of any general/dynamic modes within the device. This register contains the interrupt thresholds for BIOZ AC Lead-Off Detection (see CNFG\_GEN for more details). Unlike many CNFG registers, changes to dynamic modes do not impact FIFO operations or require a SYNCH operation (though the affected circuits may require time to settle, resulting in invalid/corrupted FIFO output voltage information during the settling interval).

Table 11. MNGR DYN (0x05) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0		
0x05	MNGR_ DYN	R/W	х	х	х	х	х	х	х	х		
				BLOFF_HI_IT[7:0]								
				BLOFF_LO_IT[7:0]								

Table 12. MNGR\_DYN (0x05) Register Functionality

INDEX	NAME	DEFAULT	FUNCTION
D[15:8]	BLOFF_HI_IT[7:0]	0xFF	BIOZ AC Lead Off Over-Range Threshold If EN_BLOFF[1:0] = 1x and the ADC output of a BIOZ measurement exceeds the symmetric thresholds defined by $\pm 2048*BLOFF_HI_IT$ for over 128ms, the BOVER interrupt bit will be asserted. For example, the default value (BLOFF_IT= 0xFF) corresponds to a BIOZ output upper threshold of 0x7F800 or about 99.6% of the full scale range, and a BIOZ output lower threshold of 0x80800 or about 0.4% of the full scale range with the LSB weight $\approx 0.4\%$ .
D[7:0]	BLOFF_LO_IT[7:0]	0xFF	BIOZ AC Lead Off Under-Range Threshold  If EN_BLOFF[1:0] = 1x and the output of a BIOZ measurement is bounded by the symmetric thresholds defined by ±32*BLOFF_LO_IT for over 128ms, the BUNDR interrupt bit will be asserted.

#### SW RST (0x08)

SW\_RST (Software Reset) is a write-only register/command that resets the MAX30002 to its original default conditions at the end of the SPI SW\_RST transaction (i.e. the 32nd SCLK rising edge). Execution occurs only if DIN[23:0] = 0x000000. The effect of a SW\_RST is identical to power-cycling the device.

Table 13. SW RST (0x08) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0	
			D[23:16] = 0x00								
0x08	SW_RST	RST R/W				D[15:8]	= 0x00				
						D[7:0]	= 0x00				

#### **SYNCH (0x09)**

SYNCH (Synchronize) is a write-only register/command that begins new BIOZ operations and recording, beginning on the internal MSTR clock edge following the end of the SPI SYNCH transaction (i.e. the 32nd SCLK rising edge). Execution occurs only if DIN[23:0] = 0x0000000. SYNCH will reset and clear the FIFO memory and the DSP filter (to midscale), allowing the user to effectively set the "Time Zero" for the FIFO records. No configuration settings are impacted. For best results, users should wait until the PLL has achieved lock before synchronizing if the CNFG\_GEN settings have been altered.

Once the device is initially powered up, it will need to be fully configured prior to launching recording operations. Likewise, anytime a change to CNFG\_GEN or CNFG\_BIOZ registers are made there may be discontinuities in the BIOZ records and possibly changes to the size of the time steps recorded in the FIFOs. The SYNCH command provides a means to restart operations cleanly following any such disturbances.

If a FIFO overflow event occurs and a portion of the record is lost, it is recommended to use the SYNCH command to recover and restart the recording, (avoiding issues with missing data).

Table 14. SYNCH (0x09) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0	
			D[23:16] = 0x00								
0x09	SYNCH	CH R/W				D[15:8]	= 0x00				
			D[7:0] = 0x00								

#### FIFO\_RST (0x0A)

FIFO\_RST (FIFO Reset) is a write-only register/command that begins a new BIOZ recording by resetting the FIFO memory and resuming the record with the next available BIOZ data. Execution occurs only if DIN[23:0] = 0x000000. Unlike the SYNCH command, the operations of any active BIOZ circuitry are not impacted by FIFO\_RST, so no settling/recovery transients apply. FIFO RST can also be used to quickly recover from a FIFO overflow state.

#### Table 15. FIFO RST (0x0A) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
						D[23:16]	] = 0x00			
0x0A	FIFO_RST	R/W				D[15:8]	= 0x00			
						D[7:0]	= 0x00			

#### INFO (0x0F)

INFO is a read-only register that provides information about the MAX30002. The first nibble contains an alternating bit pattern to aide in interface verification. The second nibble contains the revision ID. The third nibble includes part ID information.

Note: Due to internal initialization procedures, this command will not read-back valid data if it is the first command executed following either a power-cycle event, or a SW\_RST event.

#### Table 16. INFO (0x0F) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
			0	1	0	1		REV_	ID[3:0]	
0x0F	INFO	R	х	х	1	0	х	х	х	х
			х	х	х	х	х	х	х	х

### Table 17. INFO (0x0F) Register Meaning

INDEX	NAME	MEANING
D[19:16]	REV_ID[3:0]	Revision ID

#### CNFG\_GEN (0x10)

CNFG\_GEN is a read/write register which governs general settings, most significantly the master clock rate for all internal timing operations. Anytime a change to CNFG\_GEN is made, there may be discontinuities in the BIOZ record and possibly changes to the size of the time steps recorded in the FIFOs. The SYNCH command can be used to restore internal synchronization resulting from configuration changes. Note when EN\_BIOZ is logic-low, the device is in one of two ultra-low power modes (determined by EN\_ULP\_LON).

#### Table 18. CNFG\_GEN (0x10) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
			EN_ULP_LON[1:0]		FMSTR[1:0]		х	EN_BIOZ	Х	х
0x10	CNFG_ GEN	R/W	EN_BL0	OFF[1:0]	EN_DCL	OFF[1:0]	IPOL		IMAG[2:0]	
			VTH	[1:0]	EN_RB	IAS[1:0]	RBIAS	SV[1:0]	RBIASP	RBIASN

Table 19. CNFG\_GEN (0x10) Register Functionality

INDEX	NAME	DEFAULT	FUNCTION
D[23:22]	EN_ULP_LON [1:0]	00	Ultra-Low Power Lead-On Detection Enable 00 = ULP Lead-On Detection disabled 01 = Reserved. Do not use. 10 = BioZ ULP Lead-On Detection enabled. 11 = Reserved. Do not use. ULP mode is only active when the BioZ channel is powered down/disabled.
D[21:20]	FMSTR[1:0]	00	Master Clock Frequency. Selects the Master Clock Frequency (FMSTR), which also determines the BioZ timing characteristics. These are generated from FCLK, which is always $32.768$ kHz. $00 = F_{MSTR} = 32768$ Hz $01 = F_{MSTR} = 32000$ Hz $10 = F_{MSTR} = 32000$ Hz $11 = F_{MSTR} = 31968.78$ Hz
D[18]	EN_BIOZ	0	BIOZ Channel Enable 0 = BIOZ Channel disabled 1 = BIOZ Channel enabled
D[15:14]	EN_BLOFF[1:0]	00	BIOZ Digital Lead Off Detection Enable 00 = Digital Lead Off Detection disabled 01 = Lead Off Under Range Detection, 4 electrode BIOZ applications 10 = Lead Off Over Range Detection, 2 and 4 electrode BIOZ applications 11 = Lead Off Over & Under Range Detection, 4 electrode BIOZ applications AC Method, requires active BIOZ Channel, enables BOVER & BUNDR interrupt behavior. Uses BIOZ excitation current set in CNFG_BIOZ with digital thresholds set in MNGR_DYN.
D[13:12]	EN_DCLOFF	00	DC Lead-Off Detection Enable 00 = DC Lead-Off Detection disabled 01 = Reserved. Do not use. 10 = DCLOFF Detection applied to the BIP/N pins. 11 = Reserved. Do not use. DC Method, requires active selected channel, enables DCLOFF interrupt and status bit behavior. Uses current sources and comparator thresholds set below.
D[11]	DCLOFF_IPOL	0	DC Lead-Off Current Polarity (if current sources are enabled/connected) 0 = BIP - Pullup BIN – Pulldown 1 = BIP - Pulldown BIN – Pullup
D[10:8]	IMAG[2:0]	000	DC Lead-Off Current Magnitude Selection  000 = 0nA (Disable and Disconnect Current Sources)  001 = 5nA  010 = 10nA  011 = 20nA  100 = 50nA  101 = 100nA  110 = Reserved. Do not use.  111 = Reserved. Do not use.

Table 19. CNFG\_GEN (0x10) Register Functionality (continued)

INDEX	NAME	DEFAULT	FUNCTION
D[7:6]	VTH[1:0]	00	DC Lead-Off Voltage Threshold Selection $00 = V_{MID} \pm 300 \text{mV}$ $01 = V_{MID} \pm 400 \text{mV}$ $10 = V_{MID} \pm 450 \text{mV}$ $11 = V_{MID} \pm 500 \text{mV}$
D[5:4]	EN_RBIAS[1:0]	00	Enable and Select Resistive Lead Bias Mode  00 = Resistive Bias disabled  01 = Reserved. Do not use.  10 = BioZ Resistive Bias enabled if EN_BIOZ is also enabled  11 = Reserved. Do not use.  If EN_BIOZ is not asserted at the same time or prior to EN_RBIAS[1:0] being enabled, then EN_RBIAS[1:0] will remain set to 00.
D[3:2]	RBIASV[1:0]	01	Resistive Bias Mode Value Selection $00 = R_{BIAS} = 50 M\Omega$ $01 = R_{BIAS} = 100 M\Omega$ $10 = R_{BIAS} = 200 M\Omega$ $11 = Reserved. Do not use.$
D[1]	RBIASP	0	Enables Resistive Bias on Positive Input  0 = BIP is not resistively connected to V <sub>MID</sub> 1 = BIP is connected to V <sub>MID</sub> through a resistor (selected by RBIASV).
D[0]	RBIASN	0	Enables Resistive Bias on Negative Input $0 = BIN$ is not resistively connected to $V_{MID}$ 1 = BIN is connected to $V_{MID}$ through a resistor (selected by RBIASV).

<u>Table 20</u> shows BIOZ data rates that can be realized with various setting of FMSTR, along with RATE configuration bits available in the CNFG\_BIOZ register. Note FMSTR also determines the timing resolution of the CAL waveform generator.

**Table 20. Master Frequency Summary Table** 

FMSTR [1:0]	MASTER FREQUENCY (f <sub>MSTR</sub> ) (Hz)	BIOZ DATA RATES (B_RATE) (sps)
00	32,768	0 = 64 1 = 32
01	32,000	0 = 62.50 1 = 31.25
10	32,000	0 = 50 1 = 25
11	31,968	0 = 49.95 1 = 24.98

### CNFG\_BMUX(0x17)

CNFG\_BMUX is a read/write register which configures the operation, settings, and functionality of the input multiplexer associated with the BIOZ channel.

### Table 21. CNFG\_BMUX (0x17) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
			х	х	OPENP	OPENN	CALP_S	SEL[1:0]	CALN_S	SEL[1:0]
0x17	CNFG_ BMUX	R/W	х	х	CG_MODE	[1:0]	EN_BIST		RNOM[2:0]	
	Diviox		х		RMOD[2:0]		х	х	FBIS <sup>-</sup>	T[1:0]

#### Table 22. CNFG\_BMUX (0x17) Register Functionality

INDEX	NAME	DEFAULT	FUNCTION
D[21]	OPENP	1	Open the BIP Input Switch (most often used for testing and calibration)  0 = BIP is internally connected to the BIOZ channel  1 = BIP is internally isolated from the BIOZ channel
D[20]	OPENN	1	Open the BIN Input Switch (most often used for testing and calibration) 0 = BIN is internally connected to the BIOZ channel 1 = BIN is internally isolated from the BIOZ channel
D[19:18]	CALP_ SEL[1:0]	00	BIP Calibration Selection 00 = No calibration signal applied 01 = Input is connected to VMID 10 = Reserved. Do not use. 11 = Reserved. Do not use.
D[17:16]	CALN_ SEL[1:0]	00	BIN Calibration Selection 00 = No calibration signal applied 01 = Input is connected to VMID 10 = Reserved. Do not use. 11 = Reserved. Do not use.
D[13:12]	CG_ MODE[1:0]	00	BIOZ Current Generator Mode Selection 00 = Unchopped Sources with Low Pass Filter (higher noise, excellent 50/60Hz rejection, recommended for BioZ applications) 01 = Chopped Sources without Low Pass Filter (low noise, no 50/60Hz rejection, recommended for BioZ applications with digital LPF, possibly battery powered BioZ applications) 10 = Chopped Sources with Low Pass Filter (low noise, excellent 50/60Hz rejection) 11 = Chopped Sources with Resistive CM Setting (Not recommended to be used for drive currents >32μA) (low noise, excellent 50/60Hz rejection, lower input impedance)
D[11]	EN_BIST	0	BIOZ Modulated Resistance Built-In-Self-Test (RMOD BIST) Mode Enable $0$ = RMOD BIST Disabled $1$ = RMOD BIST Enabled To avoid body interference, the BIP/N switches should be open in this mode. When enabled, the DRVP/N isolation switches are opened and the DRVP/N-to-BIP/N internal switches are engaged. Also, the lead bias resistors are applied to the BIOZ inputs in $200M\Omega$ mode.

Table 22. CNFG\_BMUX (0x17) Register Functionality (continued)

INDEX	NAME	DEFAULT	FUNCTION	
D[10:8]	RNOM[2:0]	000	BIOZ RMOD BIST Nominal Resistance Selection See RMOD BIST Settings Table for details.	
D[6:4]	RMOD[2:0]	100	BIOZ RMOD BIST Modulated Resistance Selection (See RMOD BIST Settings table for details.)  000 = Modulated Resistance Value 0  001 = Modulated Resistance Value 1  010 = Modulated Resistance Value 2  011 = Reserved, Do Not Use  1xx = All SWMOD Switches Open - No Modulation (DC value = RNOM)	
D[1:0]	FBIST[1:0]	00	BIOZ RMOD BIST Frequency Selection Calibration Source Frequency Selection (FCAL) $00 = f_{MSTR}/2^{13} \qquad \text{(Approximately} \qquad 4 \text{ Hz}) \\ 01 = f_{MSTR}/2^{15} \qquad \text{(Approximately} \qquad 1 \text{ Hz}) \\ 10 = f_{MSTR}/2^{17} \qquad \text{(Approximately} \qquad 1/4 \text{ Hz}) \\ 11 = f_{MSTR}/2^{19} \qquad \text{(Approximately} \qquad 1/16 \text{ Hz}) \\ \text{Actual frequencies are determined by FMSTR selection (see CNFG_GEN for details), approximate frequencies are based on a 32,768 Hz clock (FMSTR[1:0]=00). All selections use 50% duty cycle.}$	

# Table 23. CNFG\_BMUX (0x17) RMOD BIST Settings

RNOM[2:0]	RMOD[2:0]	NOMINAL RESISTANCE (Ω)	MODULATED RESISTANCE (mΩ)
000	000 001 010 1xx	5000	2960.7 980.6 247.5 Unmodulated
001	000 001 010 1xx	2500	740.4 245.2 61.9 Unmodulated
010	000 001 010 1xx	1667	329.1 109.0 27.5 Unmodulated

Table 23. CNFG\_BMUX (0x17) RMOD BIST Settings (continued)

RNOM[2:0] AND SWNOM SWITCHES ENGAGED	RMOD[2:0]	NOMINAL RESISTANCE (Ω)	MODULATED RESISTANCE (mΩ)
011	000 001 1xx	1250	185.1 61.3 Unmodulated
100	000 001 1xx	1000	118.5 39.2 Unmodulated
101	000 001 1xx	833	82.3 27.2 Unmodulated
110	000 001 1xx	714	60.5 20.0 Unmodulated
111	000 001 1xx	625	46.3 15.3 Unmodulated

#### CNFG\_BIOZ(0x18)

CNFG\_BIOZ is a read/write register which configures the operation, settings, and function of the BIOZ channel, including the associated modulated current generator. Anytime a change to CNFG\_BIOZ is made, there may be discontinuities in the BIOZ record and possibly changes to the size of the time steps recorded in the BIOZ FIFO. The SYNCH command can be used to restore internal synchronization resulting from configuration changes.

Table 24. CNFG\_BIOZ (0x18) Register Map

REG	NAME	R/W	23/15/7	22/14/6	21/13/5	20/12/4	19/11/3	18/10/2	17/9/1	16/8/0
	CNFG		RATE		AHPF[2:0]		EXT_ RBIAS	LN_BIOZ	GAIN	<b>I</b> [1:0]
0x18	BIOZ	R/W	DHPF	[1:0]	DLPF[	1:0]	FCGEN[3:0]			
			CGMON		CGMAG[2:0]			PHOF	F[3:0]	

Table 25. CNFG\_BIOZ (0x18) Register Functionality

INDEX	NAME	DEFAULT	FUNCTION
			BIOZ Data Rate (also dependent on FMSTR selection, see CNFG_GEN):
			FMSTR = 00: f <sub>MSTR</sub> = 32,768Hz 0 = 64sps 1 = 32sps
D[23]	RATE	0	FMSTR = 01: f <sub>MSTR</sub> = 32,000Hz 0 = 62.50sps 1 = 31.25sps
			FMSTR = 10: f <sub>MSTR</sub> = 32,000 Hz 0 = 50sps 1 = 25sps
			FMSTR = 11: f <sub>MSTR</sub> = 31,968 Hz 0 = 49.95sps 1 = 24.98sps
D[22:20]	AHPF[2:0]	010	BIOZ Channel Analog High-Pass Filter Cutoff Frequency and Bypass 000 = 125Hz 001 = 300Hz 010 = 800Hz 011 = 2000Hz 100 = 3700Hz 101 = 7200Hz 11x = Bypass AHPF
D[19]	EXT_RBIAS	0	External Resistor Bias Enable  0 = Internal Bias Generator used  1 = External Bias Generator used  Note: Use of the external resistor bias will improve the temperature coefficient of all biases within the product, but the main benefit is improved control of BIOZ current generator magnitude. If enabled, the user must include the required external resistor between RBIAS and GND, and the temperature coefficent achieved will be determined by the combined performance of the internal bandgap and the external resistor.
D[18]	LN_BIOZ	0	BIOZ Channel Instrumentation Amplifier (INA) Power Mode 0 = BIOZ INA is in low power mode 1 = BIOZ INA is in low noise mode
D[17:16]	GAIN[1:0]	00	BIOZ Channel Gain Setting 00 = 10V/V 01 = 20V/V 10 = 40V/V 11 = 80V/V
D[15:14]	DHPF[1:0]	00	BIOZ Channel Digital High-Pass Filter Cutoff Frequency 00 = Bypass (DC) 01 = 0.05Hz 1x = 0.50Hz

Table 25. CNFG\_BIOZ (0x18) Register Functionality (continued)

INDEX	NAME	DEFAULT	FUNCTION
D[13:12]	DLPF[1:0]	01	BIOZ Channel Digital Low-Pass Filter Cutoff Frequency 00 = Bypass (Decimation only, no FIR filter) 01 = 4Hz 10 = 8Hz 11 = 16Hz (Available for 64, 62.5, 50, and 49.95sps BIOZ Rate selections only) Note: See Table 39 below. If an unsupported DLPF setting is specified, the 4Hz setting (DLPF[1:0] = 01) will be used internally; the CNFG_BIOZ register will continue to hold the value as written, but return the effective internal value when read back.
D[11:8]	FCGEN[3:0]	1000	BIOZ Current Generator Modulation Frequency $0000 = 4 * f_{MSTR}$ (approximately 128000Hz) $1000 = f_{MSTR}/64$ (approximately 500Hz) $0011 \approx 2 * f_{MSTR}$ (approximately 80000Hz) $1001 = f_{MSTR}/128$ (approximately 250Hz) $0010 \approx f_{MSTR}$ (approximately 40000Hz) $101x = f_{MSTR}/256$ (approximately 125Hz) $0011 \approx f_{MSTR}/2$ (approximately 18000Hz) $11xx = f_{MSTR}/256$ (approximately 125Hz) $0100 = f_{MSTR}/4$ (approximately 8000Hz) $0101 = f_{MSTR}/8$ (approximately 4000Hz) $0111 = f_{MSTR}/8$ (approximately 2000Hz) $0111 = f_{MSTR}/32$ (approximately 1000Hz) Actual frequencies determined by FMSTR selection, see CNFG_GEN register and table below for details.
D[7]	CGMON	0	BIOZ Current Generator Monitor  0 = Current Generator Monitors disabled  1 = Current Generator Monitors enabled, requires active BIOZ channel and Current Generators. Enables BCGMON interrupt and status bit behavior. Monitors current source compliance levels, useful in detecting DRVP/DRVN lead off conditions with 4 electrode BIOZ applications.
D[6:4]	CGMAG[2:0]	000	BIOZ Current Generator Magnitude $000 = Off  (DRVP \text{ and } DRVN \text{ floating, } Current \text{ Generators } Off)$ $001 = 8\mu A$ $010 = 16\mu A$ $011 = 32\mu A$ $100 = 48\mu A$ $101 = 64\mu A$ $111 = 96\mu A$ $111 = 96\mu A$ See Table 40 and 41 below for a list of allowed CGMAG settings vs. FCGEN selections.
D[3:0]	PHOFF[3:0]	0000	BIOZ Current Generator Modulation Phase Offset Phase Resolution and Offset depends on FCGEN setting: FCGEN[3:0] ≥ 0010: Phase Offset = PHOFF[3:0]*11.25° (0 to 168.75°) FCGEN[3:0] = 0001: Phase Offset = PHOFF[3:1]*22.50° (0 to 157.50°) FCGEN[3:0] = 0000: Phase Offset = PHOFF[3:2]*45.00° (0 to 135.00°)

**Table 26. Supported RATE and DLPF Options** 

CNFG_GEN	RATE		DLPF[1:0] / Dig	ital LPF Cut Off	
FMSTR[1:0]	Sample Rate	00	01	10	11
00 = 22.769	0 = 64sps	Pyroco	4.096Hz	8.192Hz	16.384Hz
00 = 32,768Hz	1 = 32sps	Bypass	4.09002	0.19202	4.096Hz
04 - 22 00011-	0 = 62.5sps	Dymana	Bypass 4.0Hz		16.0Hz
01 = 32,000Hz	1 = 31.25sps	Bypass	4.002	8.0Hz	4.0Hz
10 - 22 00011-	0 = 50sps	Dymana	4.0Hz	0.011-	16.0Hz
10 = 32,000Hz	1 = 25sps	Bypass	4.002	8.0Hz	4.0Hz
44 - 24 06011-	0 = 49.95sps	Dymana	2 00611-	7 00011-	15.984Hz
11 = 31,968Hz	1 = 25.98sps	Bypass	3.996Hz	7.992Hz	3.996Hz

Note: Combinations shown in grey are unsupported and will be internally mapped to the default settings shown.

Table 27. Actual BIOZ Current Generator Modulator Frequencies vs. FMSTR[1:0] Selection

	I	BIOZ Current Generator M	Modulation Frequency (Hz	<u>z</u> )
FCGEN[3:0]	FMSTR[1:0] = 00 f <sub>MSTR</sub> = 32,768Hz	FMSTR[1:0] = 01 f <sub>MSTR</sub> = 32,000Hz	FMSTR[1:0] = 10 f <sub>MSTR</sub> = 32,000Hz	FMSTR[1:0] = 11 f <sub>MSTR</sub> = 31,968Hz
0000	131,072	128,000	128,000	127,872
0001	81,920	80,000	80,000	81,920
0010	40,960	40,000	40,000	40,960
0011	18,204	17,780	17,780	18,204
0100	8,192	8,000	8,000	7,992
0101	4,096	4,000	4,000	3,996
0110	2,048	2,000	2,000	1,998
0111	1,024	1,000	1,000	999
1000	512	500	500	500
1001	256	250	250	250
101x, 11xx	128	125	125	125

Table 28. Allowed CGMAG Option vs. FCGEN Selections

FCGEN[3:0]	APPROXIMATE CURRENT GENERATOR MODULATION FREQUENCY (Hz)	CGMAG[2:0] OPTIONS ALLOWED	CURRENT GENERATOR MAGNITUDE OPTIONS ALLOWED (µA <sub>P-P</sub> )		
0000	12,8000				
0001	80,000	All	All		
0010	40,000	All	All		
0011	18,000				
0100	8,000	All except 111	All except 96		
0101	4,000	000, 001, 010, 011	Off, 8, 16, 32		
0110	2,000	000, 001, 010	Off, 8, 16		
0111	1,000				
1000	500	000 001	O# 9		
1001	250	000, 001	Off, 8		
101x, 11xx	125				

# **FIFO Memory Description**

The device provides read only FIFO memory for BIOZ information. The operation of this FIFO memory is detailed in the following sections.

Table 29 summarizes the method of access and data structure within the FIFO memory.

**Table 29. FIFO Memory Access and Data Structure Summary** 

REG	FIFO AND		DATA STRUCTURE (D[23:0])																						
REG	MODE	23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
0x22	BIOZ Burst		BIOZ Sample Voltage Data [19:0]							0		TA0 [2:0]	-												
0x23	BIOZ							BIOZ	Z San	nple V	oltage	e Data	a [19:	0]								0		TA0 [2:0]	-

#### **BIOZ FIFO Memory (8 Words x 24 Bits)**

The BIOZ FIFO memory is a standard circular FIFO consisting of 8 words, each with 24 bits of information. The BIOZ FIFO is independently managed by internal read and write pointers. The read pointer is updated in response to the 32nd SCLK rising edge in a normal mode read back transaction and on the (32 + n x 24)th SCLK rising edge(s) in a burst mode transaction where n = 0 to up to 31. Once a FIFO sample is marked as read, it cannot be accessed again.

The write pointer is governed internally. To aide data management and reduce  $\mu C$  overhead, the device provides a user-programmable BIOZ FIFO Interrupt Threshold (BFIT[2:0]) governing the BIOZ Interrupt bit (BINT). This threshold can be programmed with values from 1 to 8, representing the number of unread BIOZ FIFO entries required before the BINT bit will be asserted, alerting the  $\mu C$  that there is a significant amount of data in the BIOZ FIFO ready for read back (see MNGR\_INT (0x04) for details).

If the write pointer ever traverses the entire FIFO array and catches up to the read pointer (due to failure of the  $\mu$ C to read/maintain FIFO data), a FIFO overflow will occur and data will be corrupted. The BOVF STATUS and tag bits will indicate this condition and the FIFO should be cleared before continuing measurements using either a SYNCH or FIFO\_RST command—note overflow events will result in the loss of samples and thus timing information, so these conditions should not occur in well-designed applications.

Do not read beyond the last valid FIFO word to prevent possible data corruption.

#### **BIOZ FIFO Data Structure**

The data portion of the word contains the 20-bit BIOZ voltage information measured at the requested sample rate in left justified two's complement format. One bit is set to 0 and the remaining three bits of data hold important data tagging information (see details in Table 30).

Table 30. BIOZ FIFO BIOZ Data Tags (BTAG[2:0] = D[2:0])

BTAG [2:0]	DESCRIPTION	RECOMMENDED USER ACTION	DATA VALID	TIME VALID
000	Valid Sample	Log sample into BIOZ record and increment the time step. Continue to read data from the BIOZ FIFO.	Yes	Yes
001	Over/Under Range Sample	Log sample into BIOZ record and increment the time step. Determine if the data is valid or a lead off condition. Continue to read data from the BIOZ FIFO.	?	Yes
010	Last Valid Sample (EOF)	Log sample into BIOZ record and increment the time step. Suspend read of the BIOZ FIFO until more samples are available.	Yes	Yes
011	Last Over/Under Range Sample (EOF)	Log sample into BIOZ record and increment the time step. Determine if the data is valid or a lead off condition. Suspend read of the BIOZ FIFO until more samples are available.	?	Yes
10x	Unused	-	-	-
110	FIFO Empty (exception)	Discard this sample without incrementing the time base. Suspend read of the BIOZ FIFO until more samples are available.	No	No
111	FIFO Overflow (exception)	Discard this sample without incrementing the time base. Issue a FIFO_RST command to clear the FIFOs or re-SYNCH if necessary. Note the corresponding halt and resumption in all the FIFOs.	No	No

#### **BIOZ Data Tags (BTAG)**

The final three bits in the sample are used as a data tag (BTAG[2:0] = D[2:0]) to assist in managing data transfers. The BTAG structure used is detailed below.

**VALID:** BTAG = 000 indicates that BIOZ data for this sample represents both a valid voltage and time step in the BIOZ record.

**OVER or UNDER RANGE:** BTAG = 001 indicates that BIOZ data for this sample violated selected range thresholds (see MNGR\_DYN and CNFG\_GEN) and that the voltage information in the sample should be evaluated to see if it is valid or indicative of a leads-off condition. Note that while the voltage data may be invalid, samples of this type do represent valid time steps in the BIOZ record.

**VALID EOF:** BTAG = 010 indicates that BIOZ data for this sample represents both a valid voltage and time step in the BIOZ record, and that this is the last sample currently available in the BIOZ FIFO (End-of-File, EOF). The  $\mu$ C should wait until further samples are available before requesting more data from the BIOZ FIFO.

**OVER or UNDER RANGE EOF:** BTAG = 011 indicates that BIOZ data for this sample violated selected range

thresholds (see MNGR\_DYN and CNFG\_GEN) and that the voltage information in the sample should be evaluated to see if it is valid or indicates a leads-off condition. Note that while the voltage data may be invalid, samples of this type do represent valid time steps in the BIOZ record. This is also the last sample currently available in the BIOZ FIFO (End-of-File, EOF). The  $\mu C$  should wait until further samples are available before requesting more data from the BIOZ FIFO.

**EMPTY:** BTAG = 110 is appended to any requested read back data from an empty FIFO. The presence of this tag alerts the user that this FIFO data does not represent a valid sample or time step. Note that if handled properly by the  $\mu$ C, an occurrence of an empty tag will not compromise the integrity of a continuous FIFO record – this tag only indicates that the read back request was either premature or unnecessary.

**OVERFLOW:** BTAG = 111 indicates that the FIFO has overflowed and that there are interruptions or missing data in the sample records. The BIOZ Overflow (BOVF) bit is also included in the STATUS register. A FIFO\_RESET is required to resolve this situation, effectively clearing the FIFO so that valid sampling going forward is assured.

# **Typical Application Circuit**

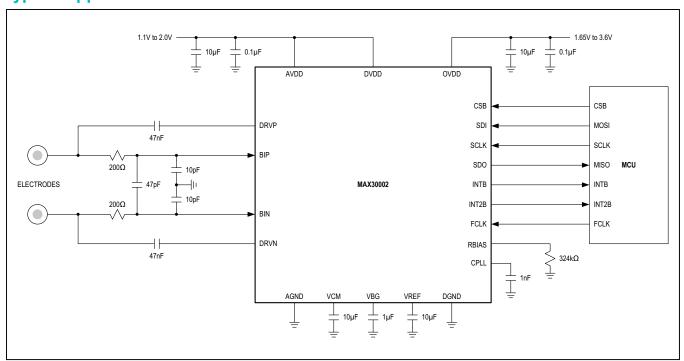


Figure 9. Two-Electrode Respiration Monitor Typical Application Circuit

### **Application Diagrams**

See <u>Figure 10</u> for an example of a clinical application for monitoring respiration using just two electrodes and with optional shared defibrillation protection circuitry. The electrode models are shown to illustrate the electrical characteristics of the physical electrodes.

# Four Electrode Respiration Monitoring Application

See <u>Figure 11</u> for an example of a clinical application for monitoring respiration using four electrodes and with optional defibrillation protection circuitry. The electrode models are shown to illustrate the electrical characteristics of the physical electrodes.

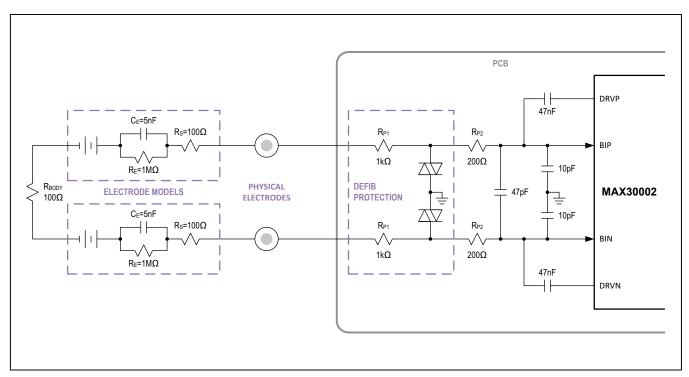


Figure 10. Two Electrode Respiration Monitoring with Optional Common Defibrillation Protection.

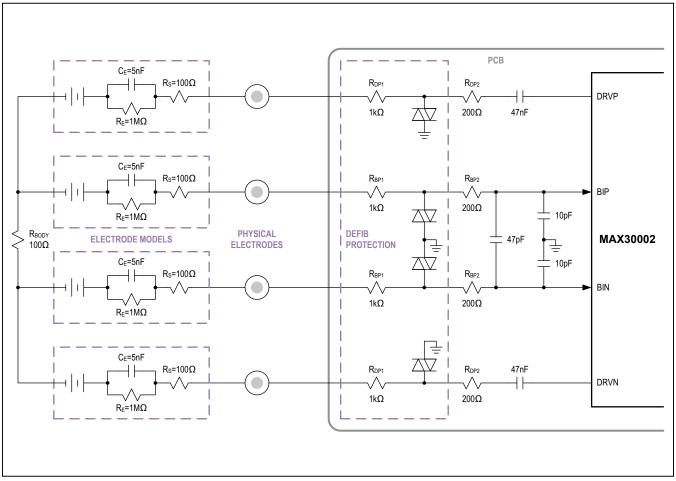


Figure 11. Four Electrode Respiration Monitoring with Optional Defibrillation Protection.

# **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX30002CTI+*	0°C TO +70°C	28 TQFN-EP**
MAX30002CTI+T*	0°C TO +70°C	28 TQFN-EP**
MAX30002CWV+	0°C TO +70°C	30WLP
MAX30002CWV+T	0°C TO +70°C	30WLP

<sup>+</sup>Denotes lead(Pb)-free/RoHS-compliant package.

### **Chip Information**

PROCESS: CMOS

### **Package Information**

For the latest package outline information and land patterns (footprints), go to <a href="www.maximintegrated.com/packages">www.maximintegrated.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
28-TQFN	T2855+8	21-0140	90-0028
30 WLP	W302L2+1	21-100074	Refer to Application Note 1891

T = Tape and reel.

<sup>\*</sup>Future product. Contact factory for availability.

<sup>\*\*</sup>EP = Exposed pad.

# MAX30002

# Ultra-Low-Power, Single-Channel Integrated Bioimpedance (BioZ) AFE

# **Revision History**

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
0	3/18	Initial release	_

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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